
	<h2>SIA430DJ-T1-GE3</h2>
	<p>Hersteller-Teilenummer: SIA430DJ-T1-GE3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET N-CH 20V 12A SC70-6</p> <p>Datenblätter:  SIA430DJ-T1-GE3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 22634 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SIA430DJ-T1-GE3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET N-CH 20V 12A SC70-6
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	22634 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	PowerPAK® SC-70-6
Supplier Device-Gehäuse	PowerPAK® SC-70-6 Single
Verlustleistung (max)	3.5W (Ta), 19.2W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	12A (Tc)
Rds On (Max) @ Id, Vgs	13.5 mOhm @ 7A, 10V
VGS (th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	18nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	800pF @ 10V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)



















































SIA430DJ-T1-GE3 ist neu im Original, Suche SIA430DJ-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SIA430DJ-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SIA430DJ-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SIA431DJ-T1 VISHAY SIA431DJ-T1 VISHAY</p>	 <p>SIA431DJ VISHAY SIA431DJ VISHAY</p>	 <p>SIA427DJ-T1-GE3 Electro-Films (EFI) / Vishay MOSFET P-CH 8V 12A SC-70-6</p>	 <p>SIA430DJ-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 20V 12A SC70-6</p>
 <p>SIA430DJT-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 20V 12A SC70-6</p>	 <p>SIA427DJ-T1-GE3 Vishay / Siliconix MOSFET P-CH 8V 12A SC-70-6</p>	 <p>SIA430DJT-T1-GE3 VISHAY VISHAY QFN-6</p>	 <p>SIA429DJT-T1-GE3 Electro-Films (EFI) / Vishay MOSFET P-CH 20V 12A SC-70</p>

heiße Teile

Mehr

 SIA411DJ-T1-GE3	 SIA411DJ-T1-GE3	 SIA413DJ-T1-GE3	 SIA413DJ-T1-GE3	 SIA413DJ-T4-GE3
 SIA414DJ-T1-GE3	 SIA414DJ-T1-GE3	 SIA415DJ-T1-GE3	 SIA415DJ-T1-GE3	 SIA417DJ-T1-GE3
 SIA417DJ-T1-GE3	 SIA419DJ	 SIA419DJ-T1-GE3	 SIA419DJ-T1-GE3	 SIA421DJ-T1-GE3
 SIA421DJ-T1-GE3	 SIA425EDJ-T1-GE3	 SIA425EDJ-T1-GE3	 SIA426DJ-T1-GE3	 SIA426DJ-T1-GE3
 SIA427DJ-T1-GE3	 SIA427DJ-T1-GE3	 SIA429DJT-T1-GE3	 SIA429DJT-T1-GE3	 SIA430DJ-T1-GE3
 SIA431DJ	 SIA431DJ-T1	 SIA431DJ-T1-GE3	 SIA431DJ-T1-GE3	 SIA432DJ-T1-GE3
 SIA432DJ-T1-GE3	 SIA433EDJ	 SIA433EDJ-T1-GE3	 SIA433EDJ-T1-GE3	 SIA436DJ-T1-GE3
 SIA436DJ-T1-GE3	 SIA443DJ-T1-GE3	 SIA443DJ-T1-GE3	 SIA444DJT-T1-GE3	 SIA444DJT-T1-GE3
 SIA445EDJ-T1-GE3	 SIA445EDJ-T1-GE3	 SIA447DJ-T1-GE3	 SIA447DJ-T1-GE3	 SIA448DJ-T1-GE3
 SIA448DJ-T1-GE3	 SIA449DJ-GE3	 SIA450DJ-T1-GE3	 SIA450DJ-T1-GE3	 SIA4528-100K

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